# NSN 5962-01-108-7867

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-108-7867

# Body Length:

Between 0.755 inches and 0.785 inches

# Body Width:

Between 0.265 inches and 0.300 inches

## **Body Height:**

Between 0.155 inches and 0.175 inches

## **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

## Storage Tempurature Range:

-65.0/+150.0 degrees celsius

# Features Provided:

Hermetically sealed and monolithic and positive outputs and programmable and schottky and w/decoded output and 3-state output

## Inclosure Material:

Ceramic and glass

## Inclosure Configuration:

Dual-in-line

# **Output Logic Form:**

Transistor-transistor logic

# Input Circuit Pattern:

10 input

**Terminal Surface Treatment:** 

Solder

#### Voltage Rating And Type Per Characteristic:

5.5 volts power source

#### **Time Rating Per Chacteristic:**

25.00 nanoseconds propagation delay time, low to high level output and 25.00 nanoseconds propagation delay time, high to low level output

#### Memory Device Type:

Rom

#### Test Data Document:

13499-351-7769 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

#### **Terminal Type And Quantity:**

16 printed circuit

#### Shelf Life:

N/a

#### Unit Of Measure:

--

#### Demilitarization:

Yes - demil/mli

#### Fiig:

A458a0